



Analysis of Resonant-Cavity Light-Emitting Diodes

CROSSLIGHT
Software Inc.

Contents

- About RCLED.
- Crosslight's model.
- Example of an InGaAs/AlGaAs RCLED with experimental verification.
- Example of a VCSEL-like RCLED of GaAs/AlGaAs MQW.
- RCLED with detuned DBR.
- RCLED with long cavity.
- Conclusions.



About RCLED

- RCLED takes advantage of microcavity effects to enhance spontaneous emission.
- Narrower spectrum linewidth.
- Superior directionality of emission with better LED-fiber coupling.
- Potential as light source for recent plastic optical fiber (POF)-based local area networks.

Crosslight RCLED model

- Self-consistent calculation of material spontaneous emission rate based on rigorous quantum well/dot spectrum theories coupled with 2/3D simulation of current injection from the Crosslight APSYS drift-diffusion solver.
- Coupling of spontaneous emission with microcavity modes based on theory of C. H. Henry (1986) [1].
- Henry's theory has been extended from waveguide to RCLED by proper accounting of mode densities in a quasi-2D/3D emission situation.
- Photon recycling effects taken into account by accurate determination of photon power density inside the RCLED and self-consistent model of material gain/loss of the quantum wells/dots.

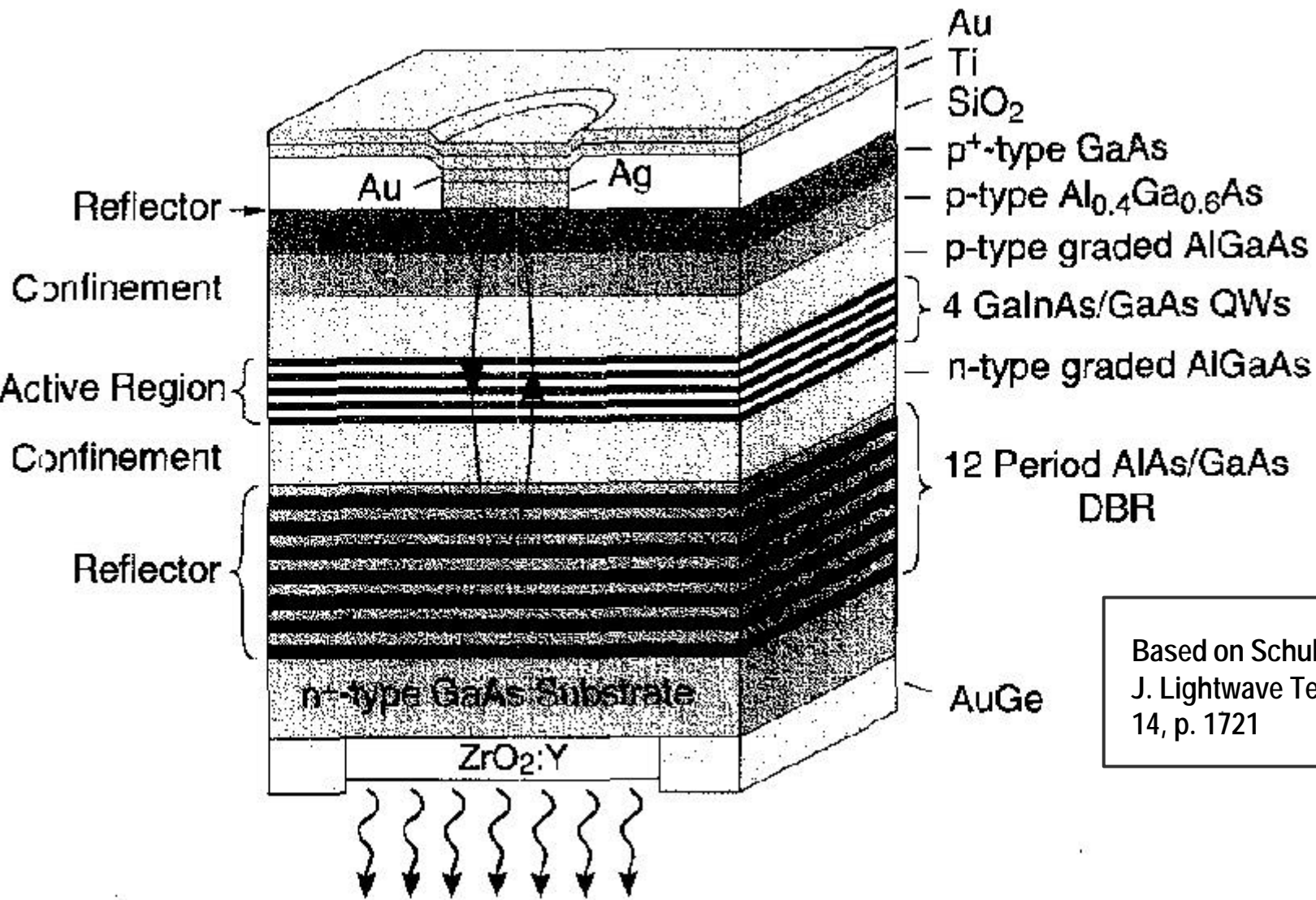
[1] C. H. Henry, "Theory of spontaneous emission noise in open resonators and its application to lasers and optical amplifiers," J. Lightwave Technol., vol. LT-4, pp. 288--297, March 1986.



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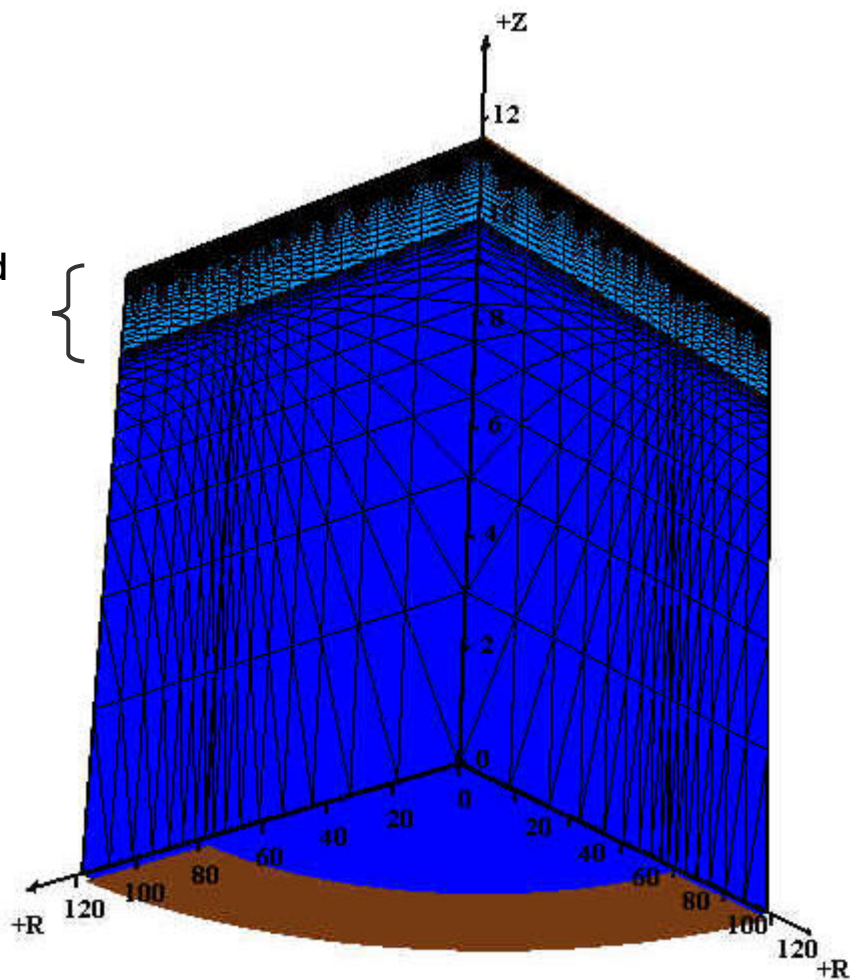
Structure



Based on Schubert et. al,
J. Lightwave Technol., vol.
14, p. 1721

Simulation Mesh

MQW and
Optical
Region



File Name : rc.sid_0004

File Type : APSYS

Variable Name :

Material Number

3D Cube Contour Parameters :

X Range : 0 - 118

Y Range : 0 - 11.6044

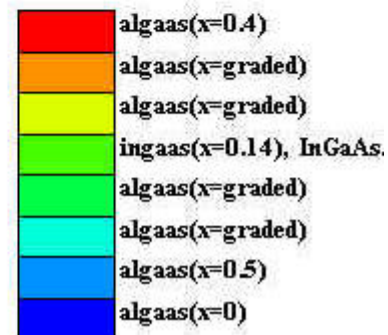
Z Range : 0 - 0

X Cut Line Num : 20

Y Cut Line Num : 20

Z Cut Line Num : 20

Material Number

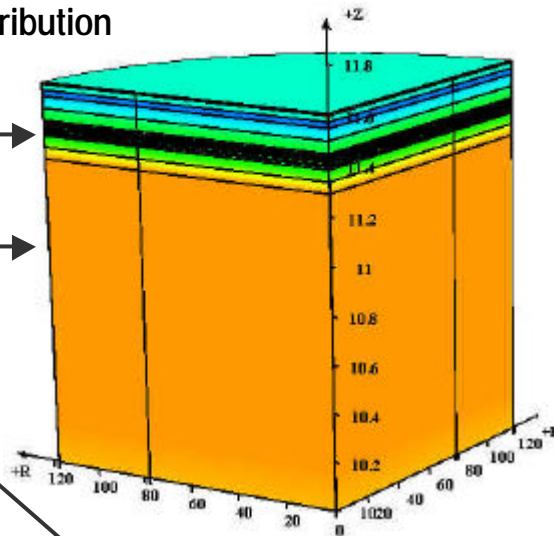


2/3D Drift-Diffusion Model

3D Potential distribution

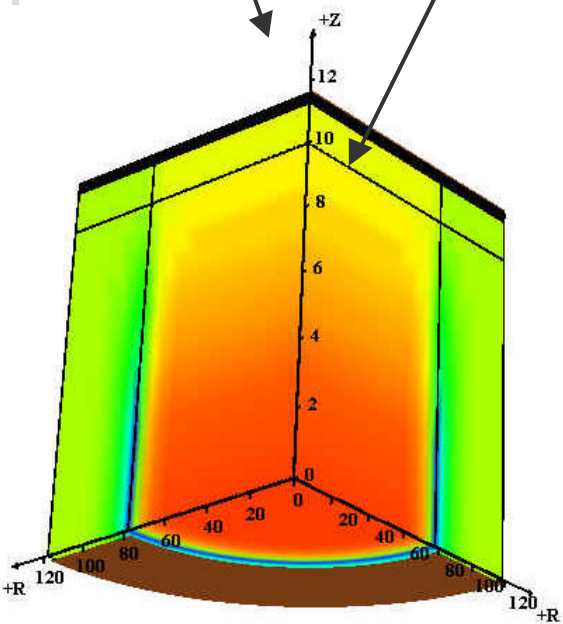
MQW Region

DBR Region



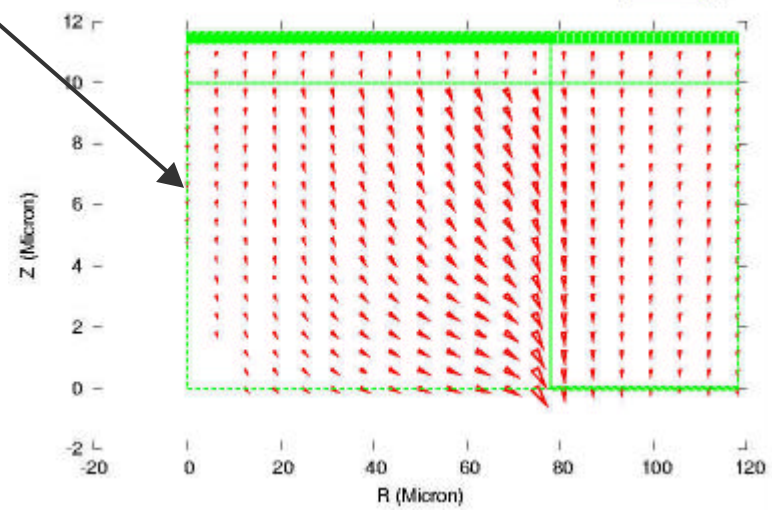
File Name : rc.cut_0006
 File Type : AP SYS
 Variable Name :
 Potential (volt)
 3D Cube Contour Parameters :
 X Range : 0 - 118
 Y Range : 10 - 11.6044
 Z Range : 0 - 0
 X Cut Line Num : 20
 Y Cut Line Num : 20
 Z Cut Line Num : 20

Distribution of y-component of electronic current

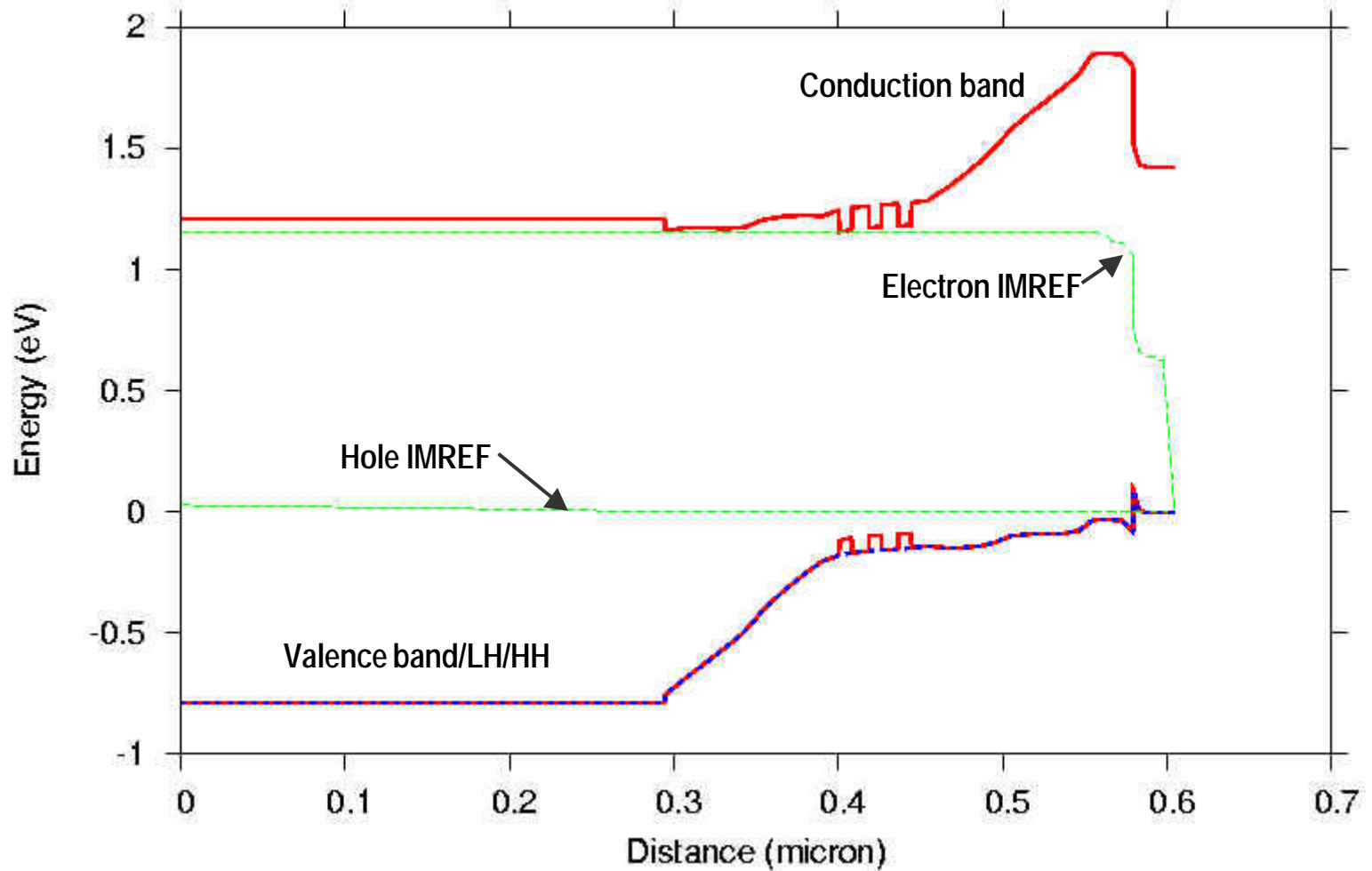


File Name : rc.std_0004
 File Type : AP SYS
 Variable Name :
 Elec_Curr_y (A/cm^2)
 3D Cube Contour Parameters :
 X Range : 0 - 118
 Y Range : 0 - 11.6044
 Z Range : 0 - 0
 X Cut Line Num : 20
 Y Cut Line Num : 20
 Z Cut Line Num : 20

Elec_Curr_y (A/cm^2)
 0
 -10
 -20
 -30
 -40
 -50
 -60
 -70
 -80



True Physical Simulation in 3D



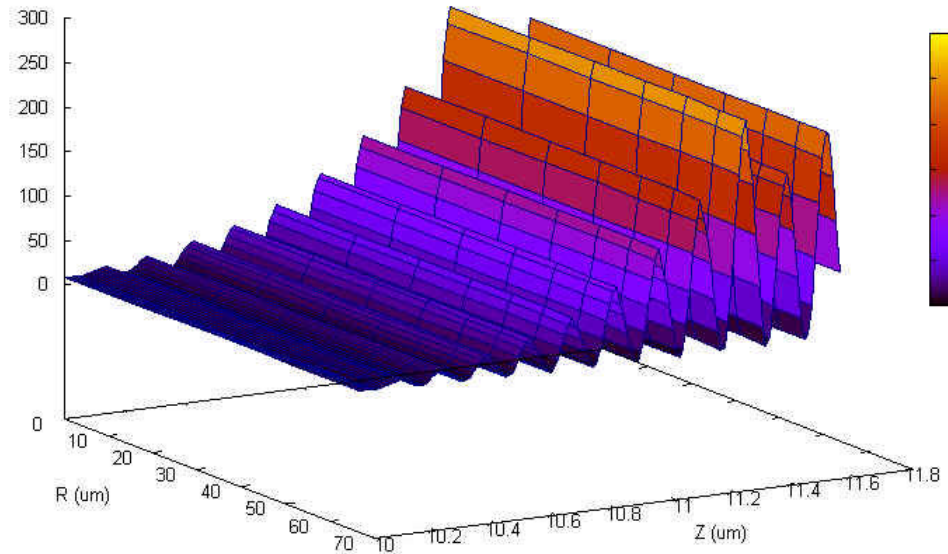
True 3D simulation of band structure physics including MQW strain effects. Current flow and self-heating may be included self-consistently in 3D.

Standing Wave and Carrier Generation

Power density relative to spontaneous emission power in z-direction

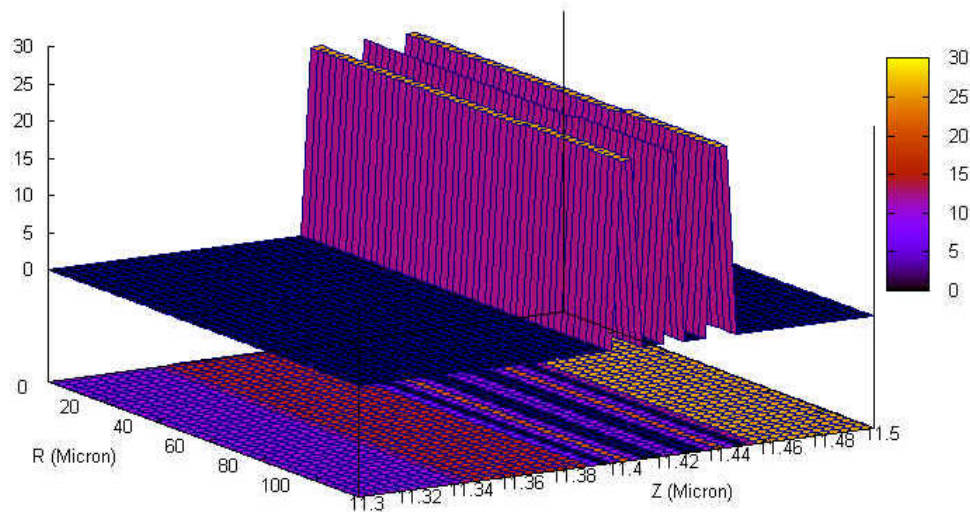


Rel. Power



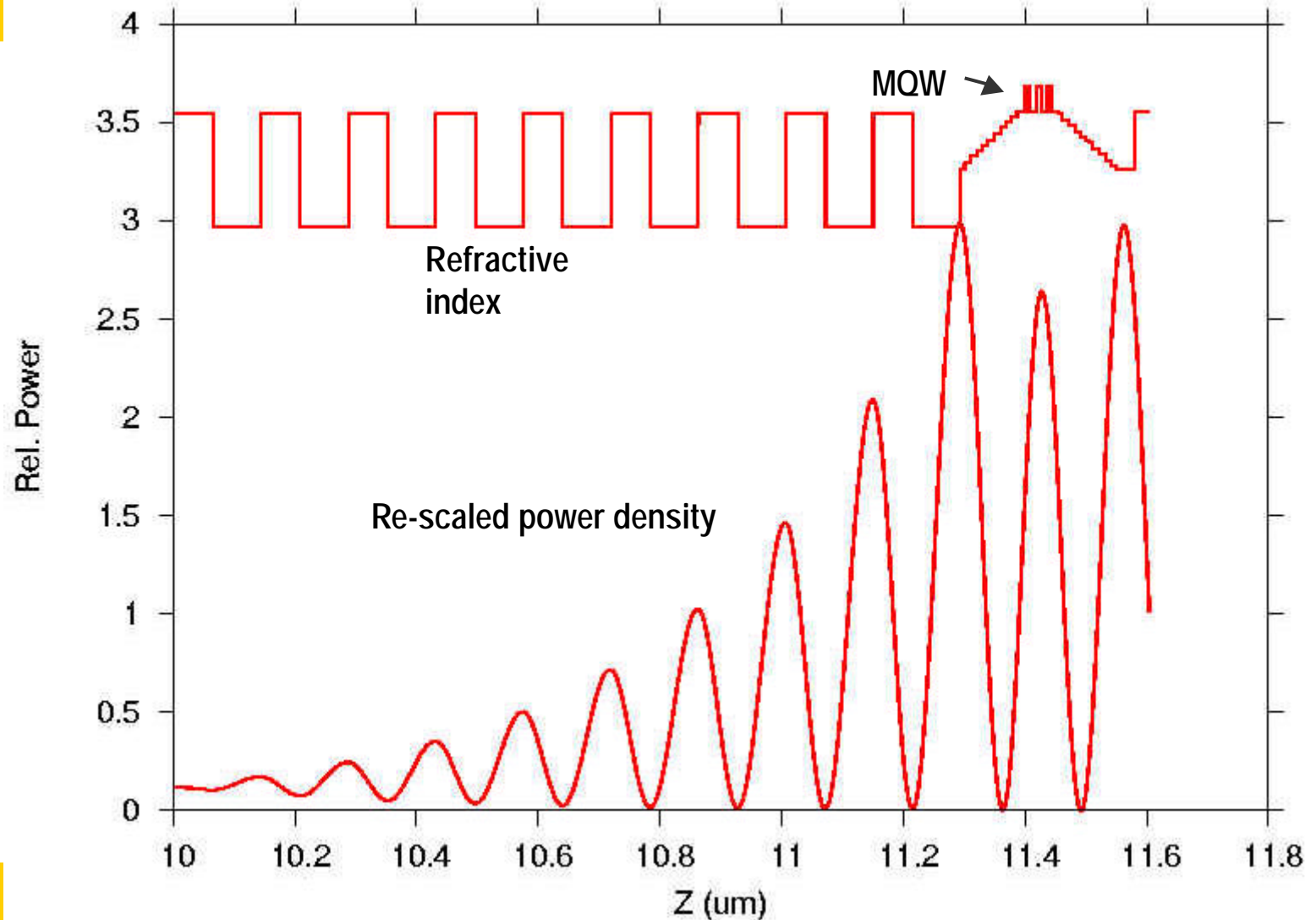
Opt_Gen (1/cm^3/s)

File:rc.plt



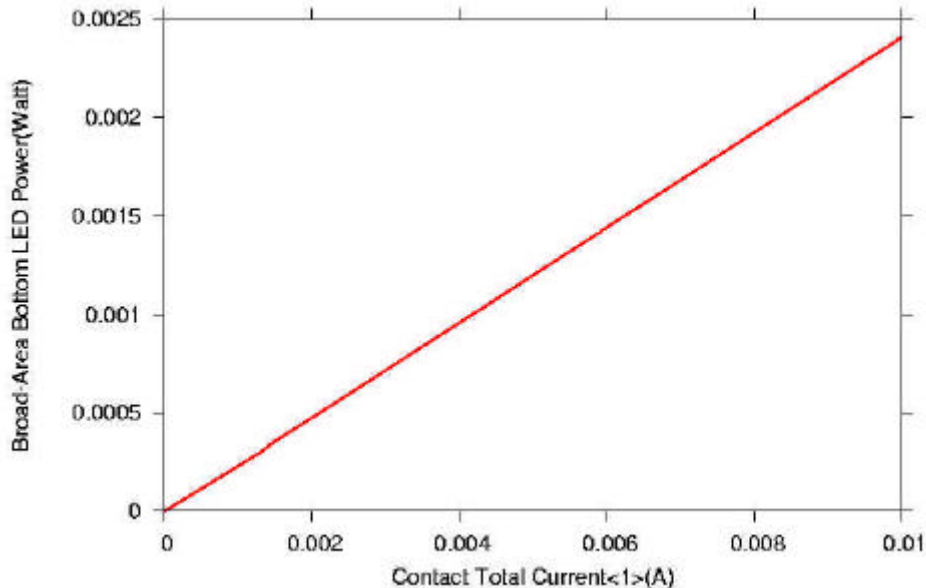
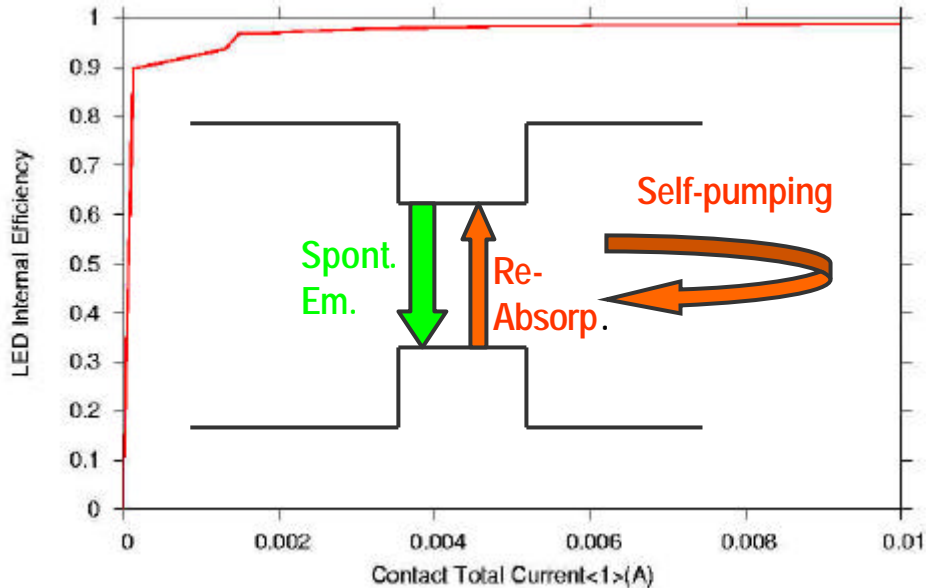
Carrier generation rate due to high optical power within the LED cavity. Absorption at MQW calculated self-consistently using interband transition models.

Standing Wave and Index



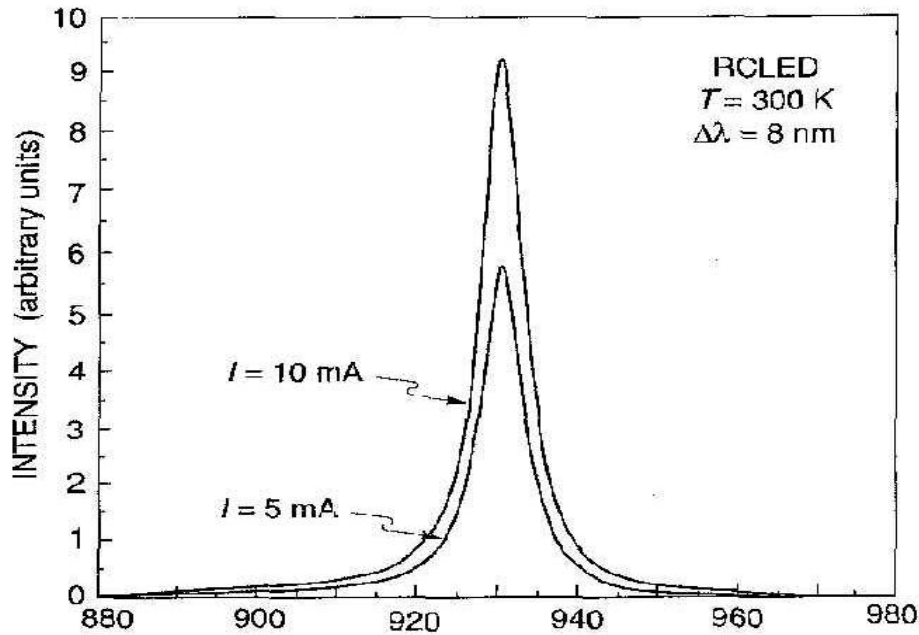
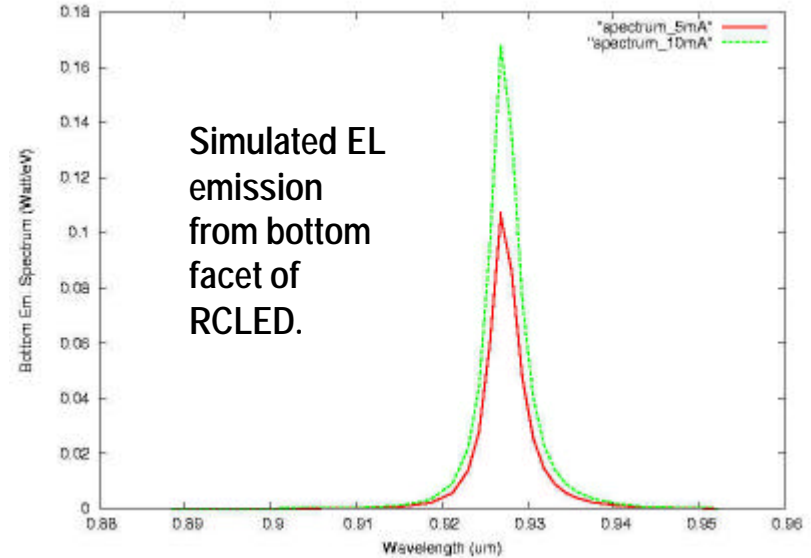
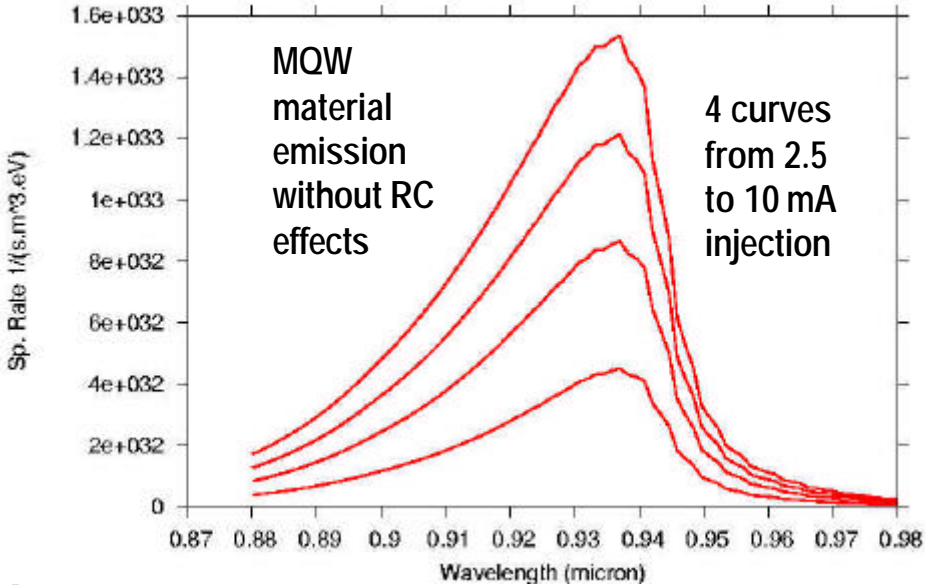
Remark: The reflection phase of the Ag. Mirror is adjusted so that antinode of standing wave aligns with the MQW region.

Photon Recycling and IQE



- High mirror reflectivity \rightarrow higher photon density in cavity under resonant condition.
- Re-absorbed photons \rightarrow higher photo carrier densities (self-photo-pumping).
- Higher carrier concentration \rightarrow more photon emission by spontaneous emission (enhanced by microcavity resonance).
- Actual spontaneous emission rate substantially higher than current injection rate.
- IQE calculation = spontaneous emission rate subtracting photon absorption rate, dividing current injection rate.

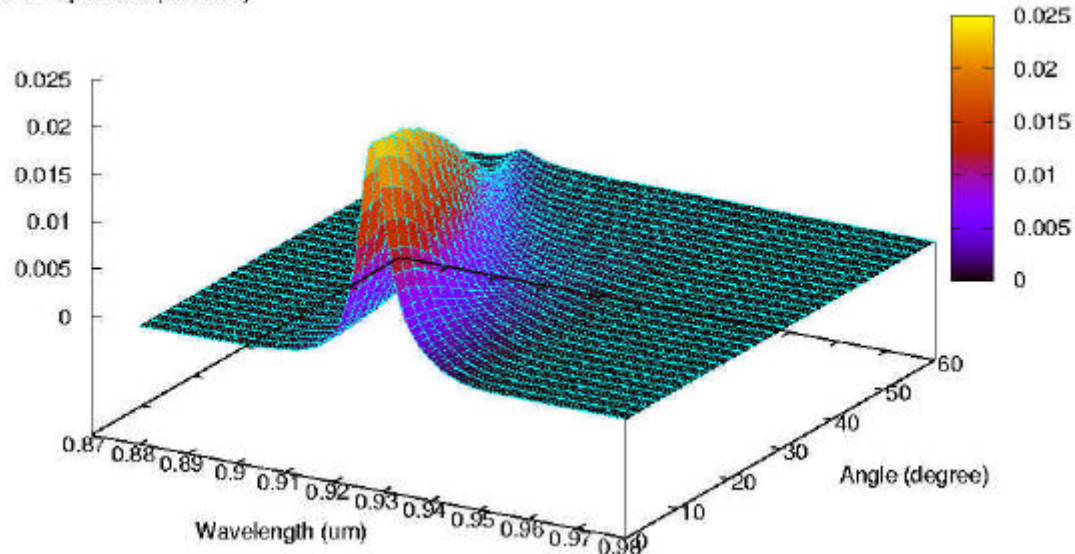
Improvement in Spectrum Linewidth



Experimental Data taken from Schubert et. al, J. Lightwave Technol., vol. 14, p. 1721

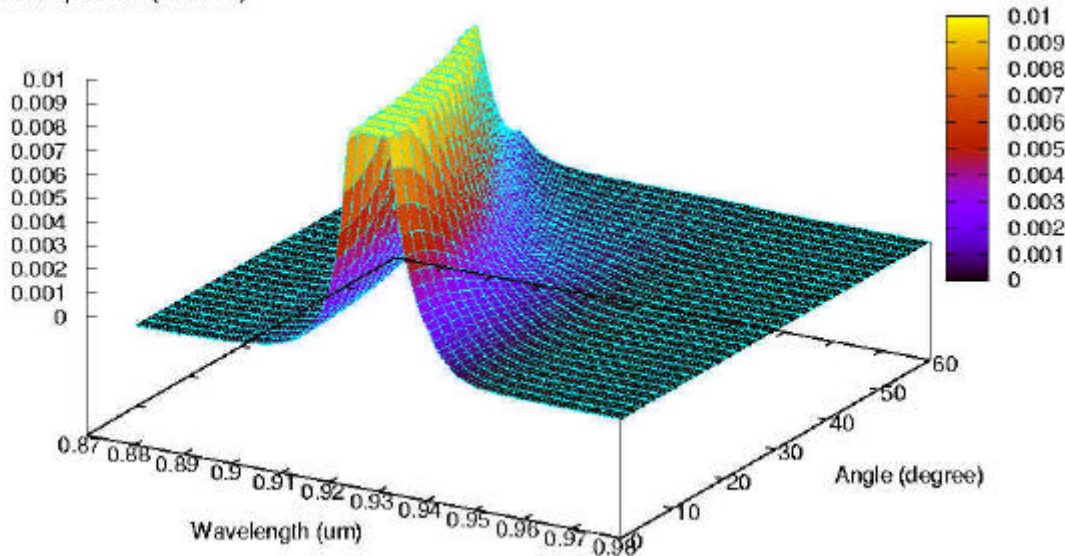
Angle Dependence in EL Spectrum

Bottom Em. Spectrum (Watt/eV)



Remark: For well tuned DBR /cavity-length and high Q cavity, only a single emission peak at normal direction is significant.

Bottom Em. Spectrum (Watt/eV)

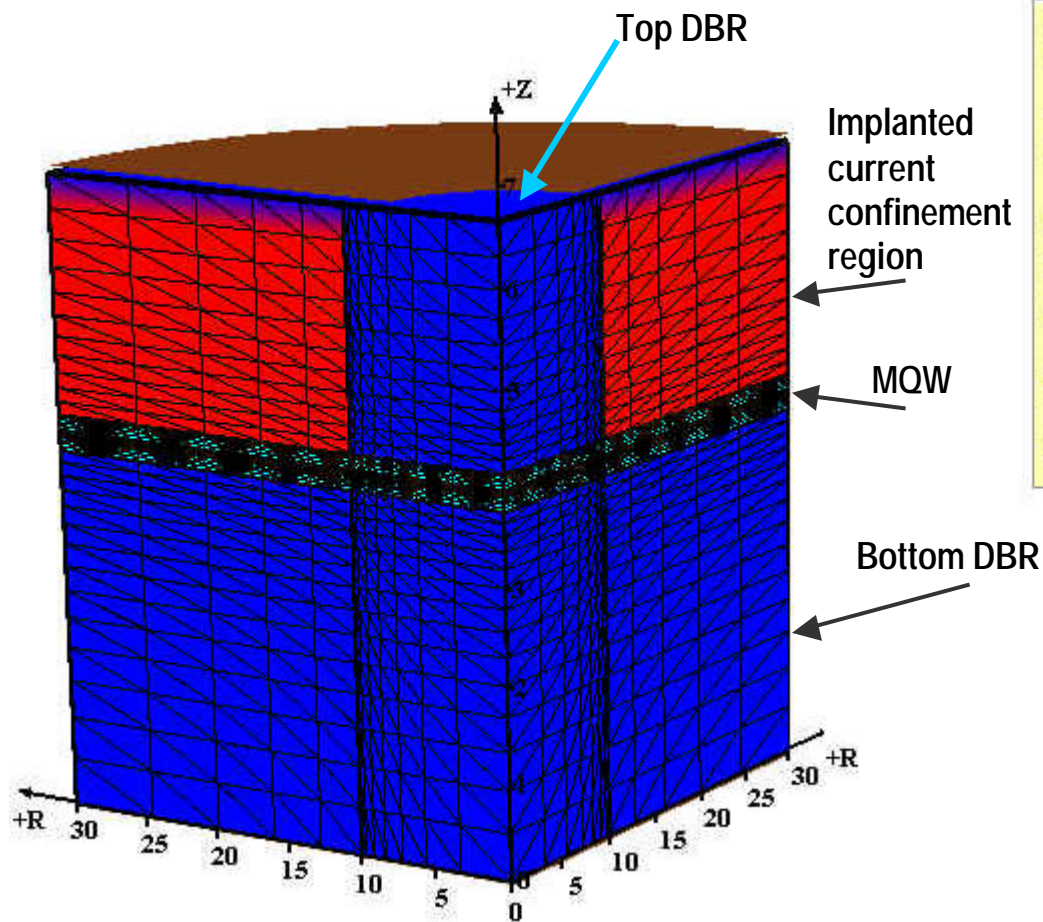


More details
near low
intensity region

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Structure of AlGaAs RCLED



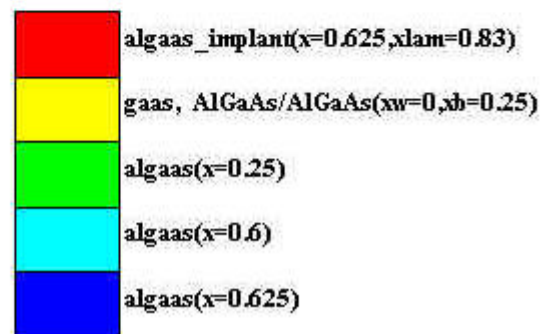
File Name : rcled.sid_0005
File Type : APSYS

Variable Name :
Material Number :

3D Cube Contour Parameters :
X Range : 0 - 30
Y Range : 0 - 6.663
Z Range : 0 - 0

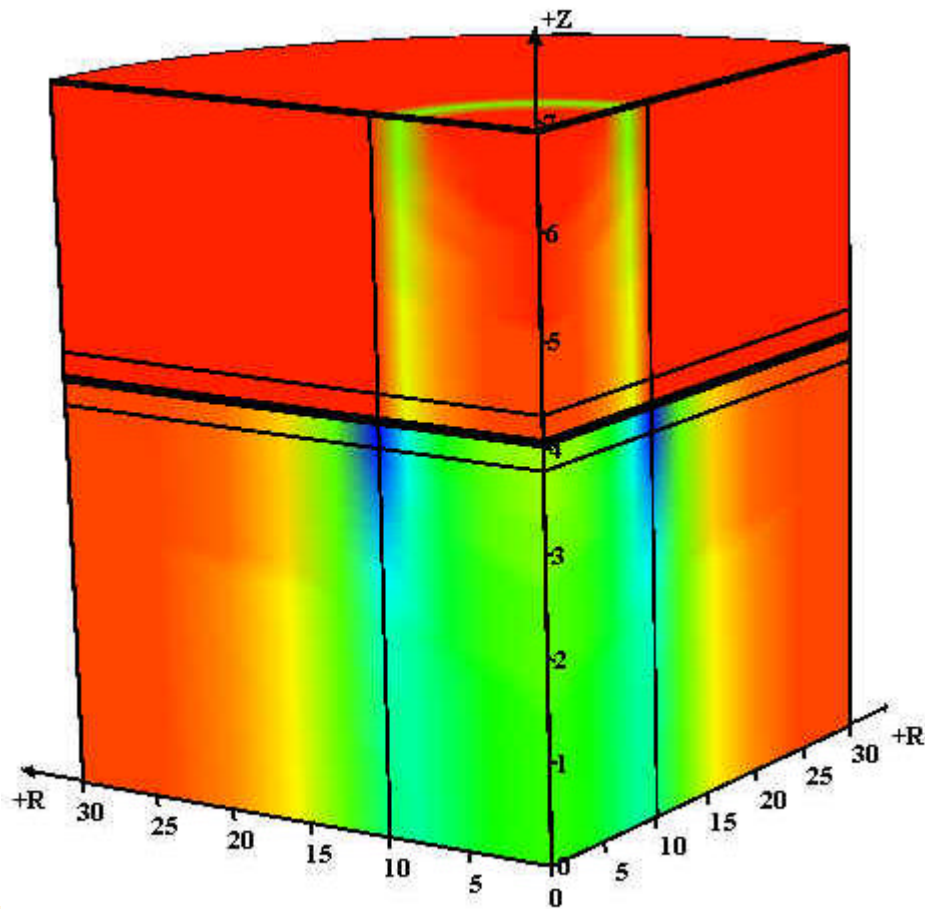
X Cut Line Num : 20
Y Cut Line Num : 20
Z Cut Line Num : 20

Material Number



A VCSEL-like structure with fewer layer pairs in top DBR to help power extraction. Ion implantation is used to form current confinement.

2/3 Dim Drift-Diffusion Model



File Name : rcled.std_0005

File Type : APSYS

Variable Name :

Elec_Curr_y (A/cm²)

3D Cube Contour Parameters :

X Range : 0 - 30

Y Range : 0 - 6.921

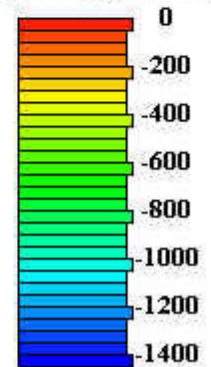
Z Range : 0 - 0

X Cut Line Num : 20

Y Cut Line Num : 20

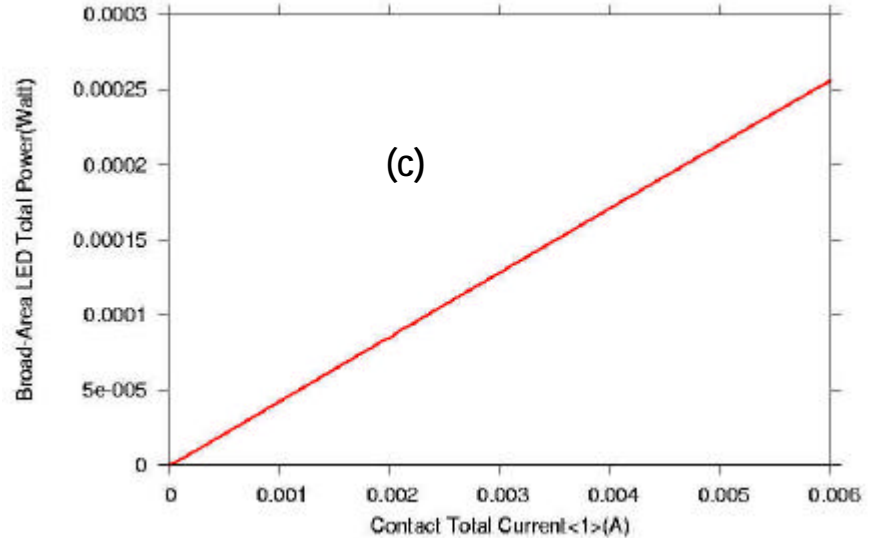
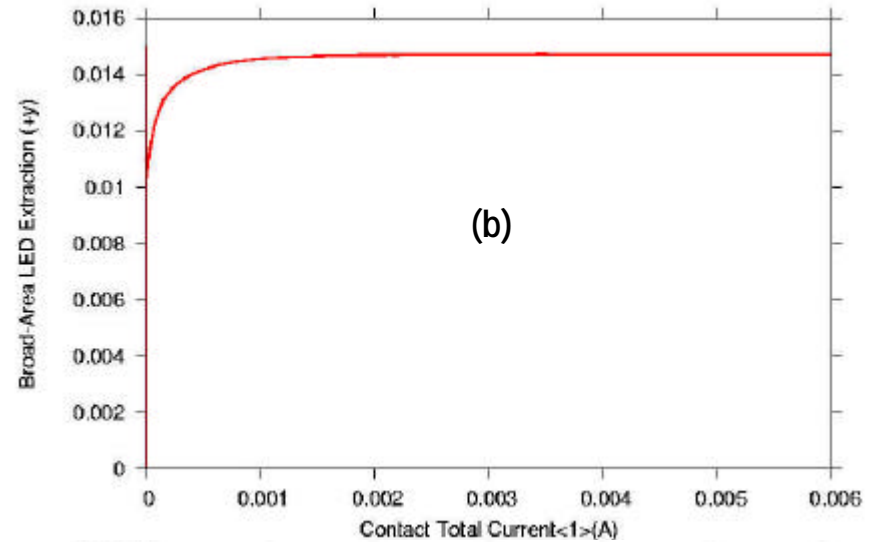
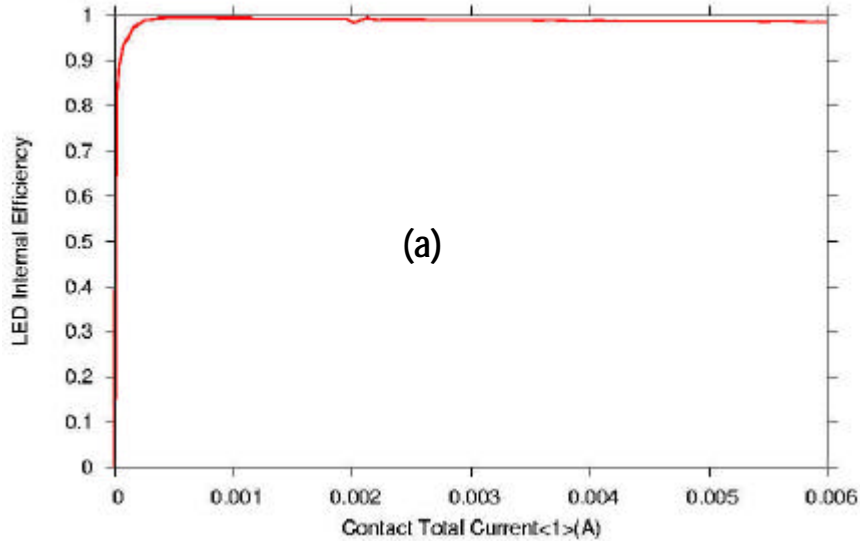
Z Cut Line Num : 20

Elec_Curr_y (A/cm²)



Y-component of electron current distribution in RCLED. Please note the strong (blue) current crowding area which causes optical gain to help amplify the optical waves there.

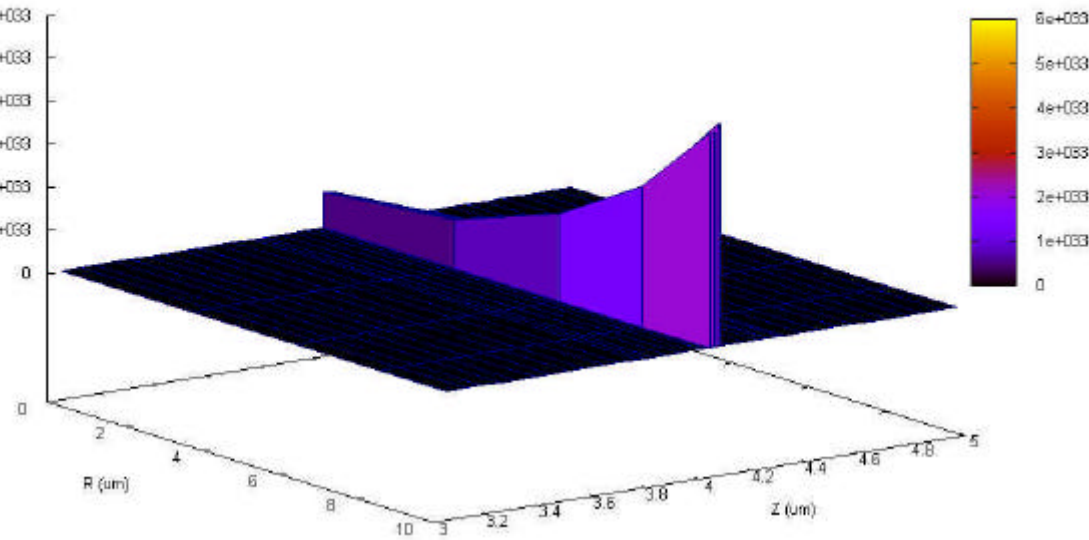
RCLED Performance



- (a) Internal efficiency of near unity.
- (b) Extraction efficiency from top facet.
- (c) Total EL power versus injection current.

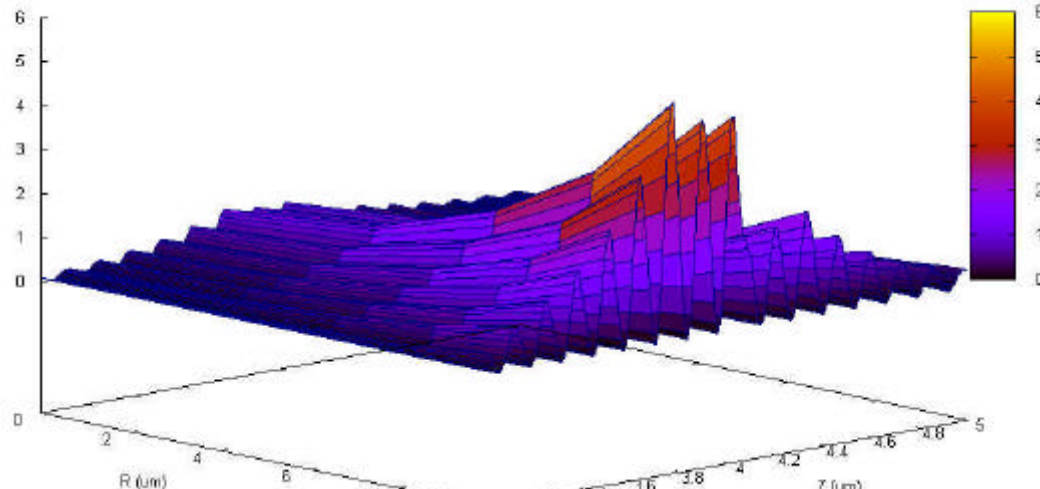
Current Crowding Effects

Em. Rate (1/m³s)



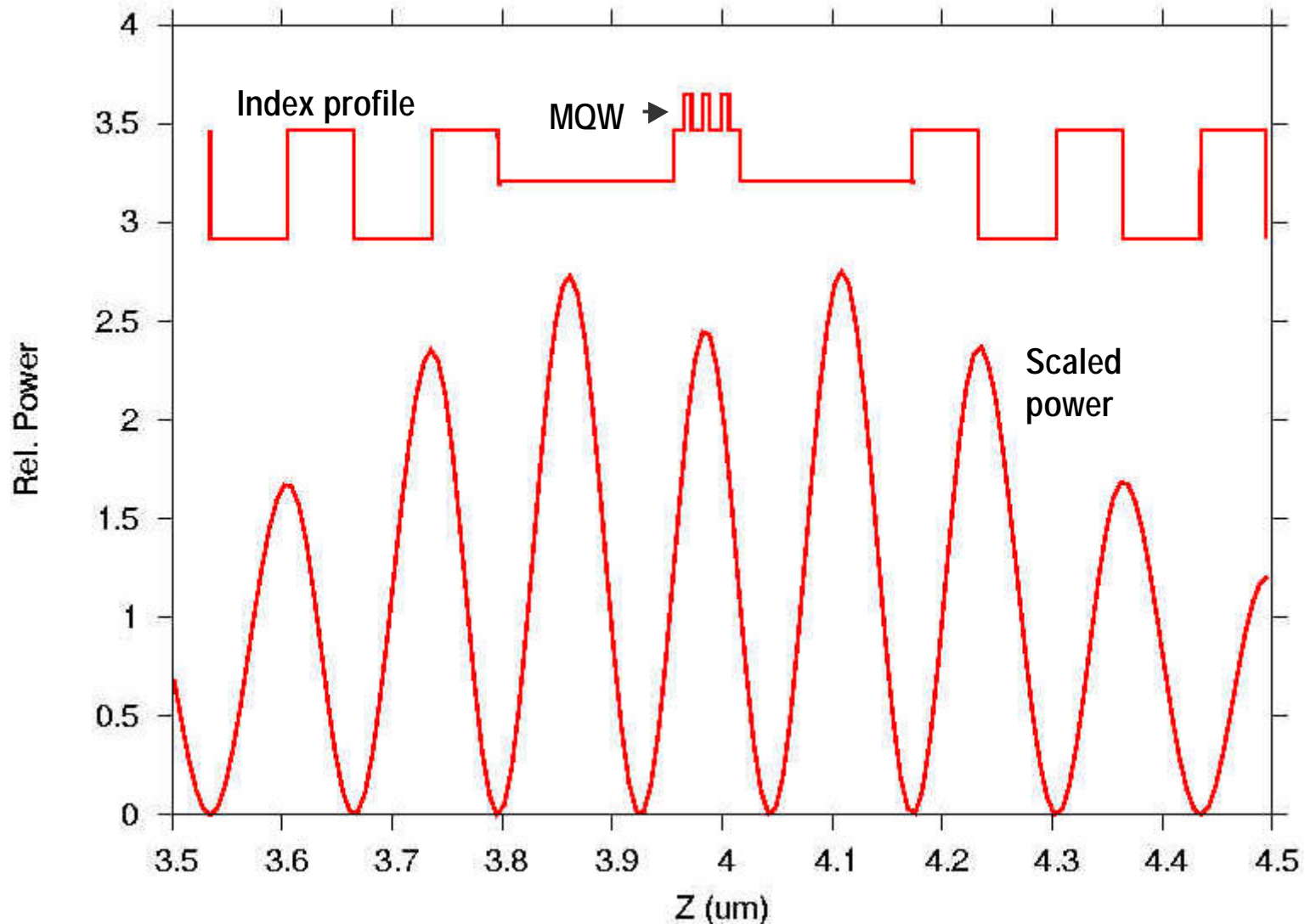
MQW spontaneous emission distribution under top aperture. Lateral distribution is due to current crowding.

Rel. Power



Standing wave shows strong lateral variation due to gain/spontaneous emission rate distribution.

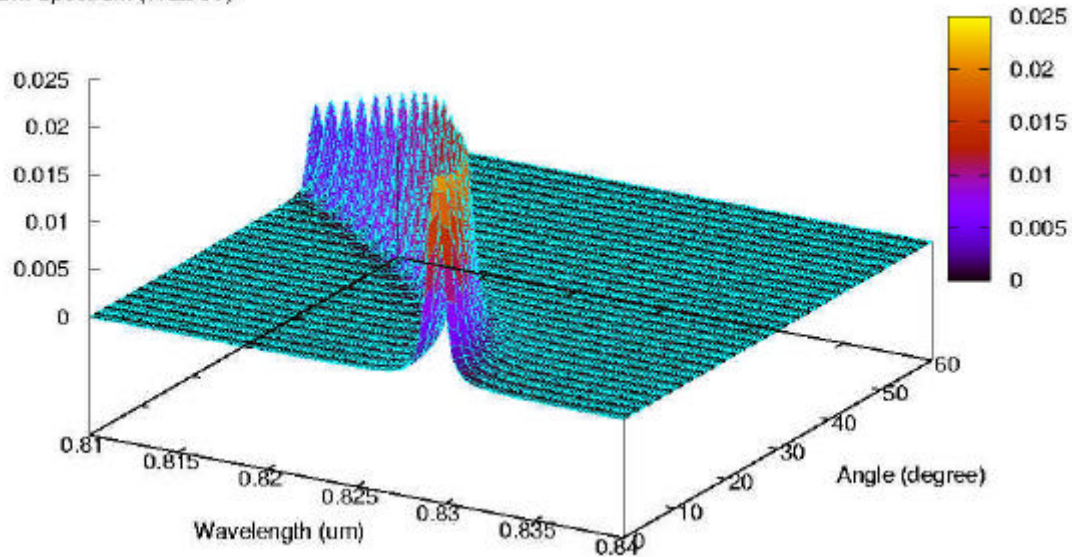
Standing Wave Alignment



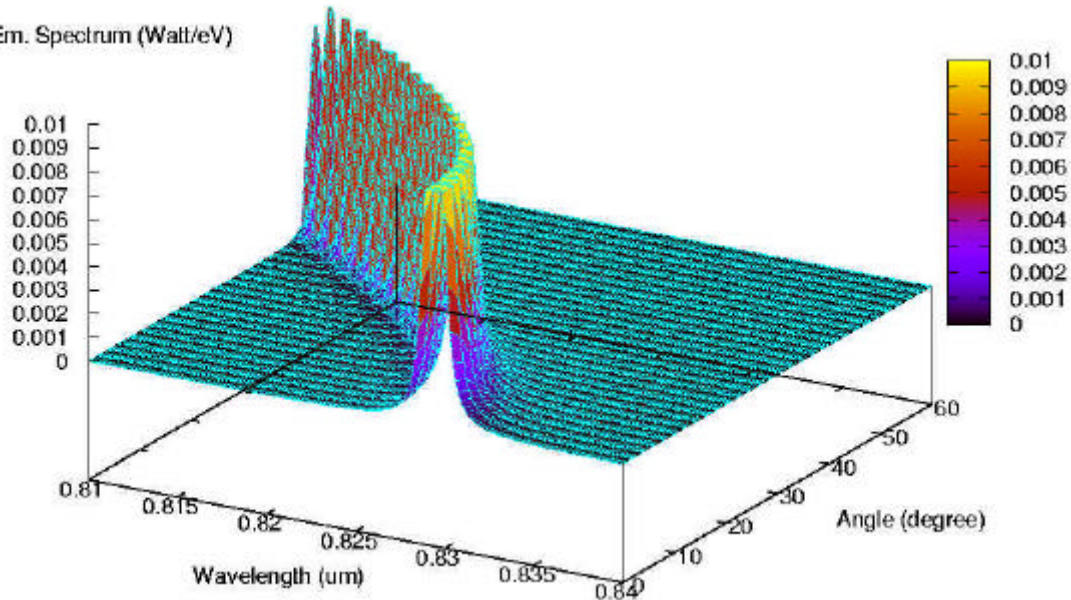
Remark: Effective cavity length near the MQW should be $(n+1/2)$ wavelength to ensure antinode of standing wave aligns with MQW.

Angular dependence of EL spectrum

Top Em. Spectrum (Watt/eV)



Top Em. Spectrum (Watt/eV)



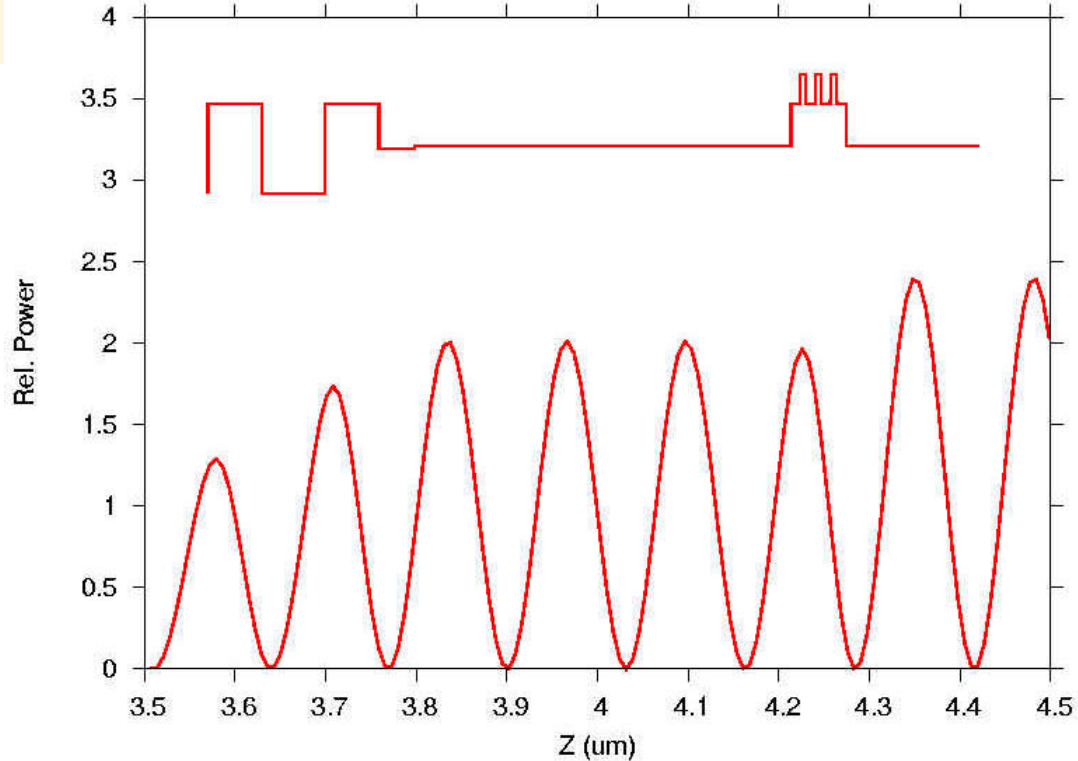
Detailed view of lower power regime of the above



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Detuning DBR/Cavity

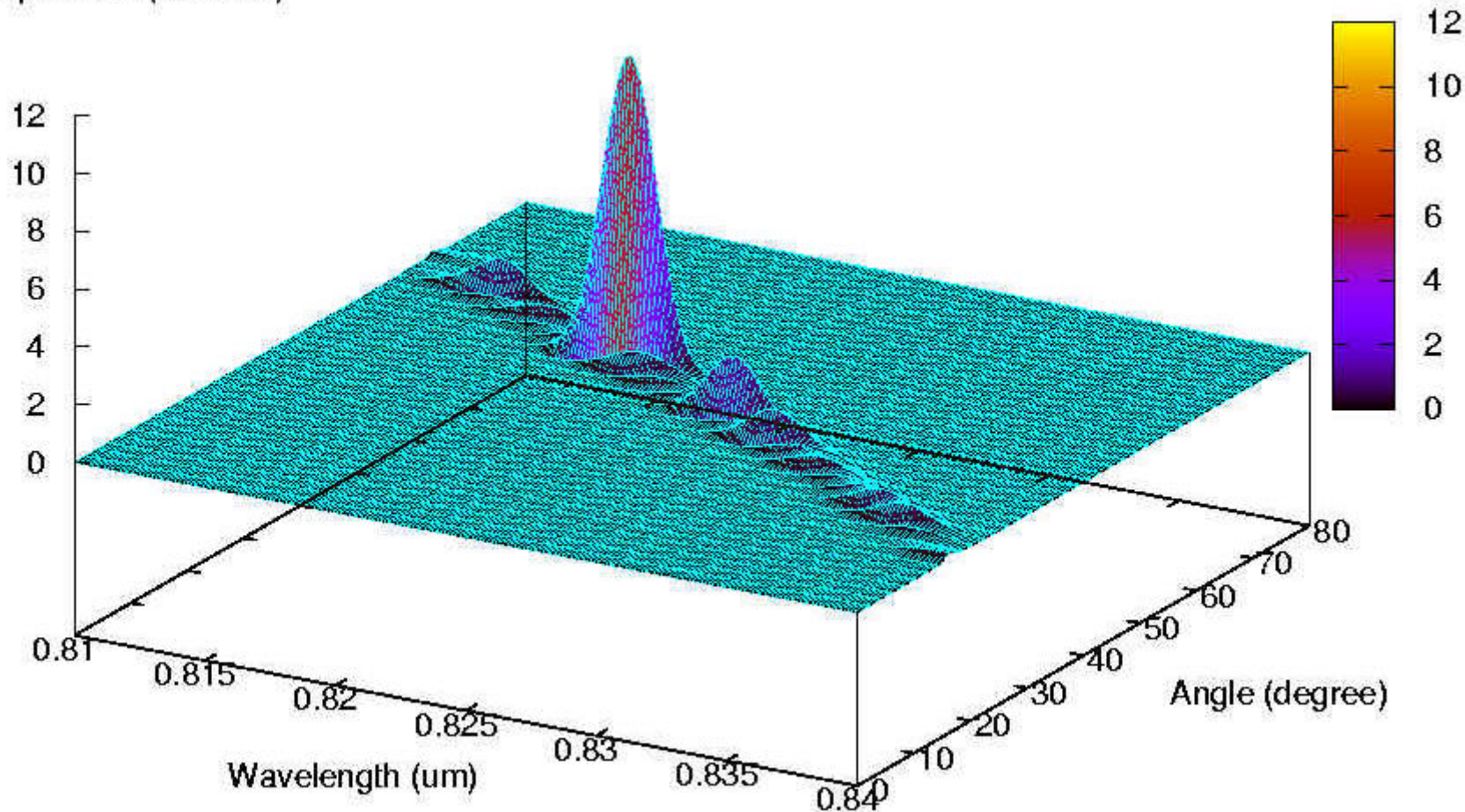


Alignment of wave at oblique maximum power direction with refractive index profile.

- There may be applications of RCLED to control the direction of major resonant peak at an oblique angle.
- Take similar VCSEL-like structure with longer cavity and slightly reduced DBR periods.
- Detuning at normal direction.

Engineering the Emission Angle

Top Em. Spectrum (Watt/eV)



Remark: Major emission at an oblique angle means ring-like emission pattern in real space.

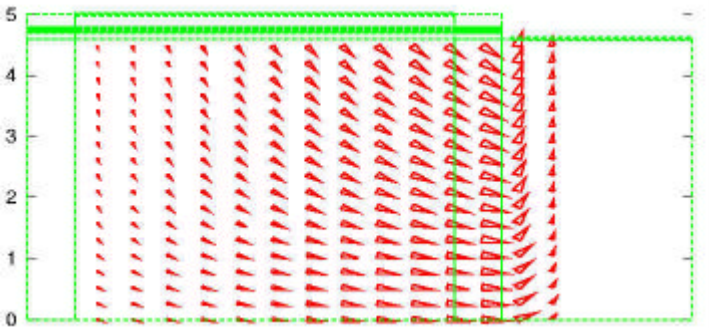
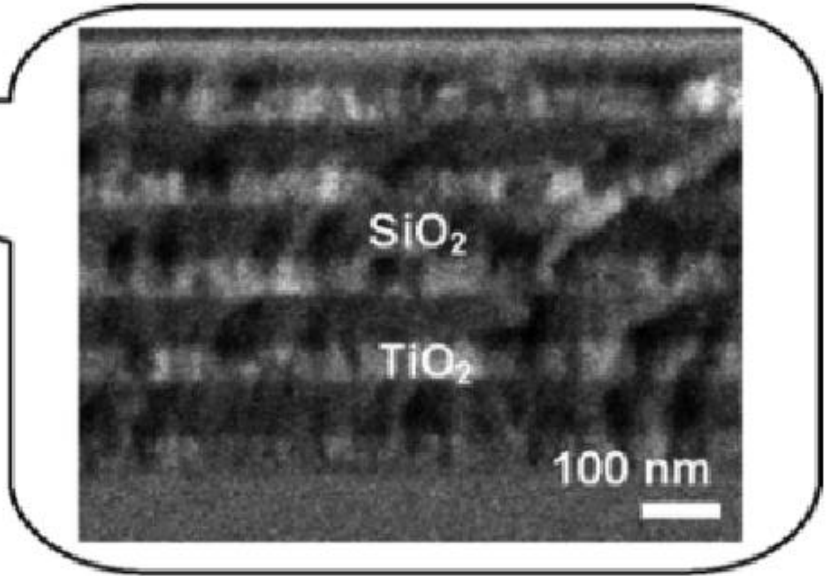
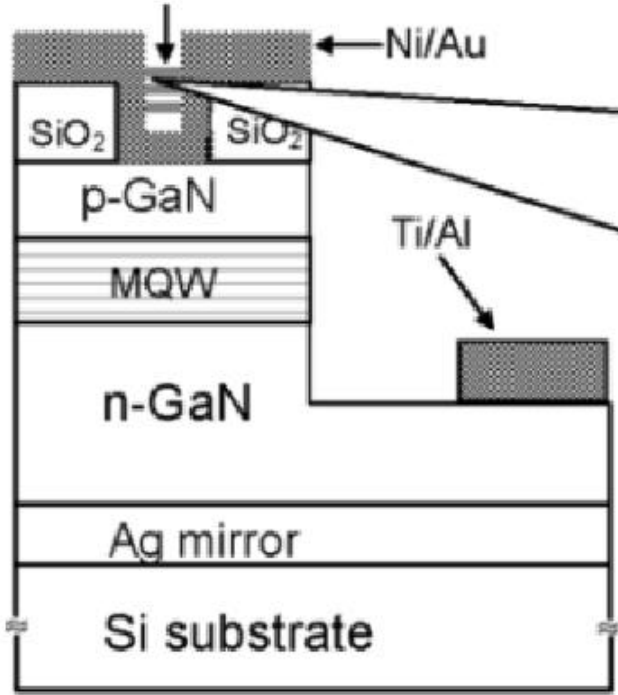
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InGaN LED Structure

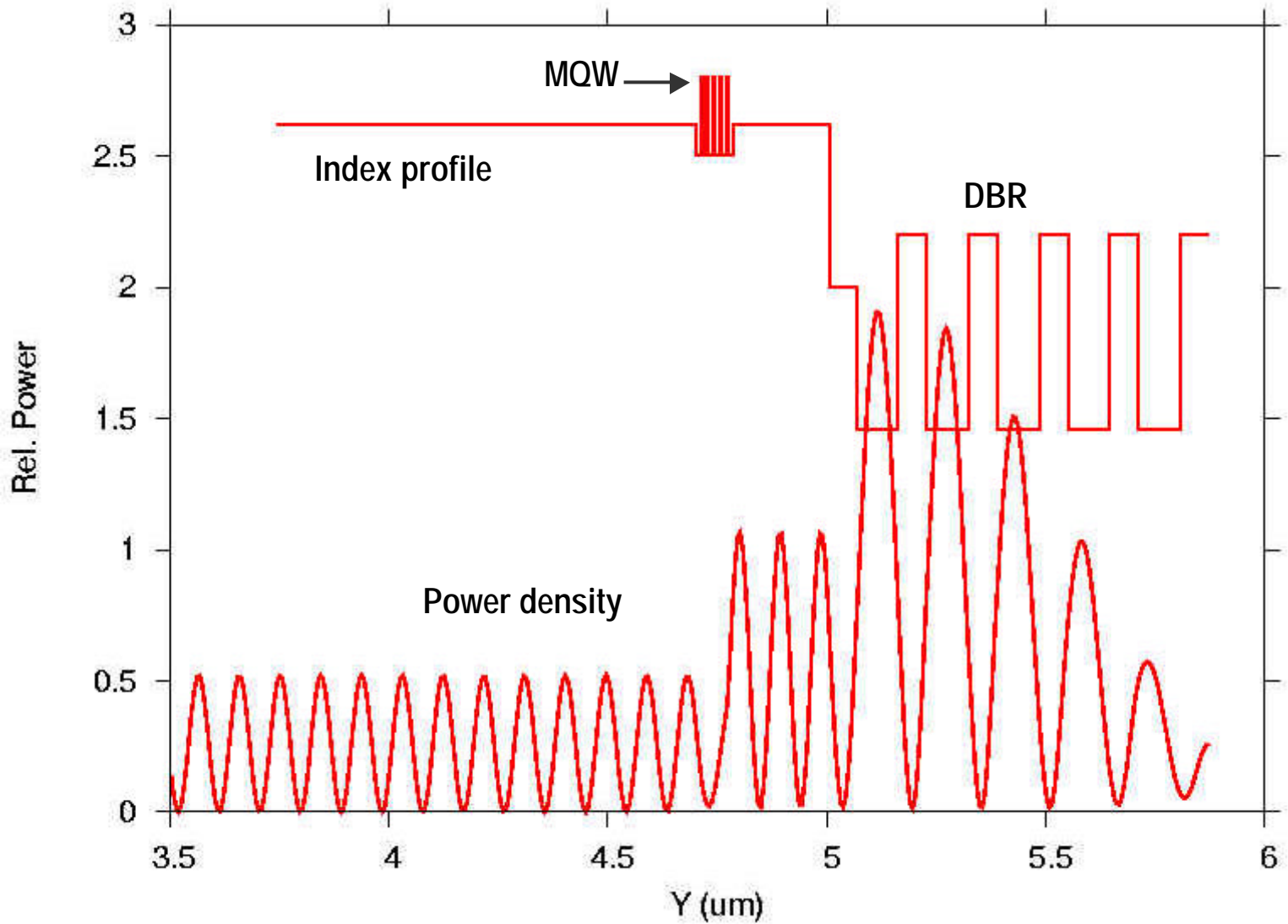
Structure taken from: Horng et. al. IEEE Photonic Tech. Lett., Vol. 18, p. 457, 2006

5 period $\text{TiO}_2/\text{SiO}_2$ DBR

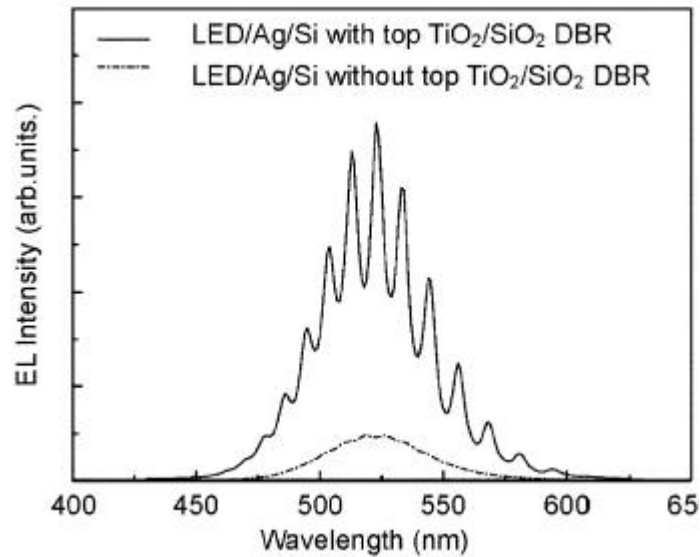


Simulated electron current flow pattern.

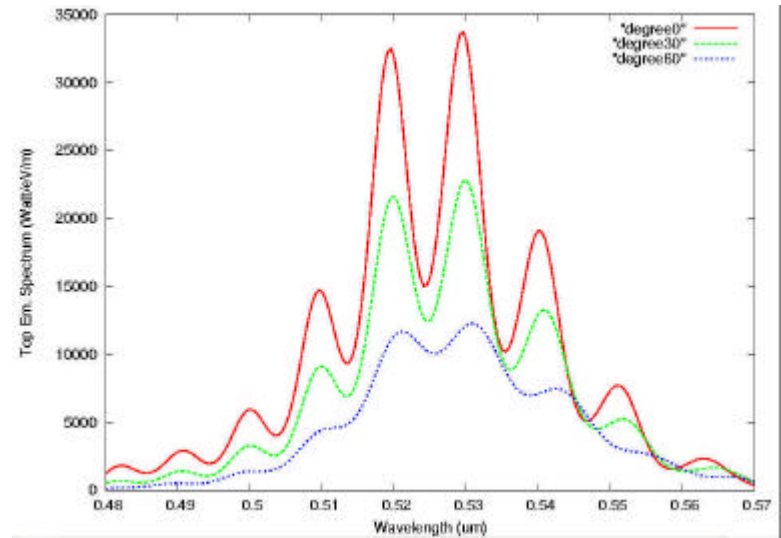
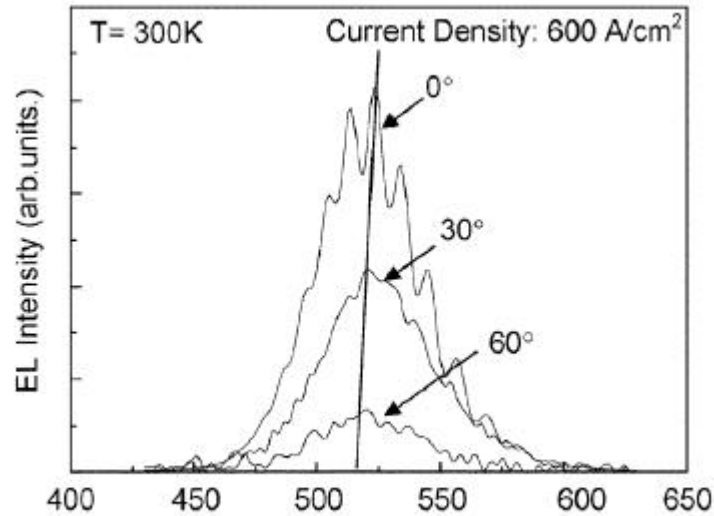
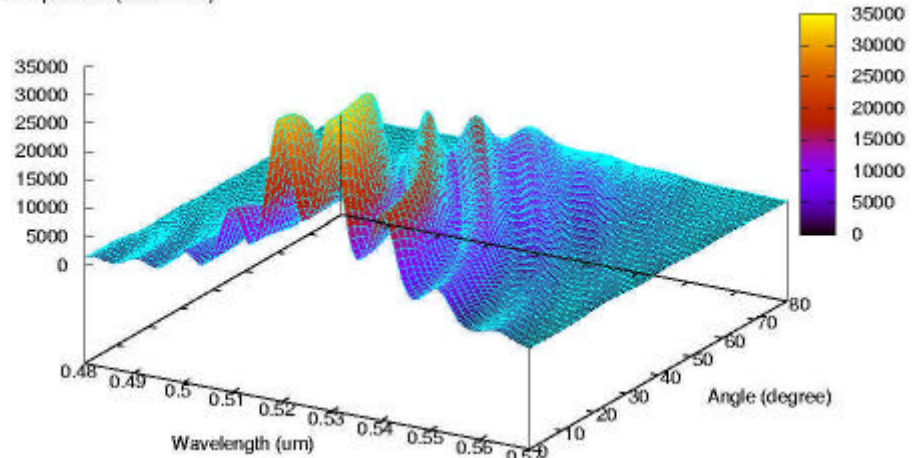
Standing Wave at Normal Direction



Multiple Resonance Peaks as Compared with Experiment



Top Em. Spectrum (Watt/m²eV)



Angle-resolved EL spectrum of InGaN RCLED sample.

Conclusions

- A comprehensive physical model of resonant cavity has been incorporated into Crosslight's APSYS/LED modules.
- Based on rigorous theory describing interaction of spontaneous emission spectrum with microcavity modes.
- Resonant effects in spatial, spectral and angular dimensions have been obtained in reasonable agreement with experiments.
- Self-consistent integration with the main APSYS simulator enables all-in-one analysis and design approach.